Single, Dual, Quad Low Voltage, Rail-to-Rail Operational Amplifiers

The LMV821, LMV822, and LMV824 are operational amplifiers with low input voltage offset and drift vs. temperature. In spite of low quiescent current requirements these devices have 5 MHz bandwidth and 1.4 V/µs slew rate. In addition they provide rail-to-rail output swing into 600 Ω loads. The input common-mode voltage range includes ground, and the maximum input offset voltage is only 3.5 mV. Substantially large capacitive loads can be driven by simply adding a pullup resistor or isolation resistor.

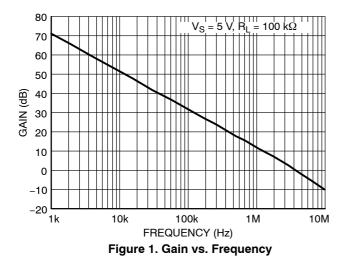
The LMV821 (single) is available in a space–saving SC70–5 while the dual and quad also come in ultra small SOIC and TSSOP packages.

Features

- Low Offset Voltage: 3.5 mV
- Very low Offset Drift: $1.0 \,\mu V/^{\circ}C$
- High Bandwidth: 5 MHz
- Rail-to-Rail Output Swing into a 600 Ω load
- Capable of driving highly capacitive loads
- These Devices are Pb-Free and are RoHS Compliant

Typical Applications

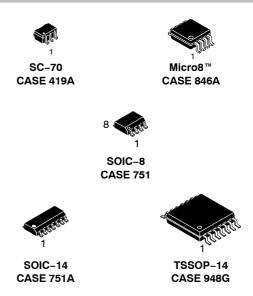
- Notebook Computers
- PDAs
- Modem Transmitter/ Receivers





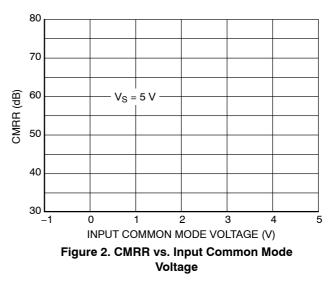
ON Semiconductor®

http://onsemi.com

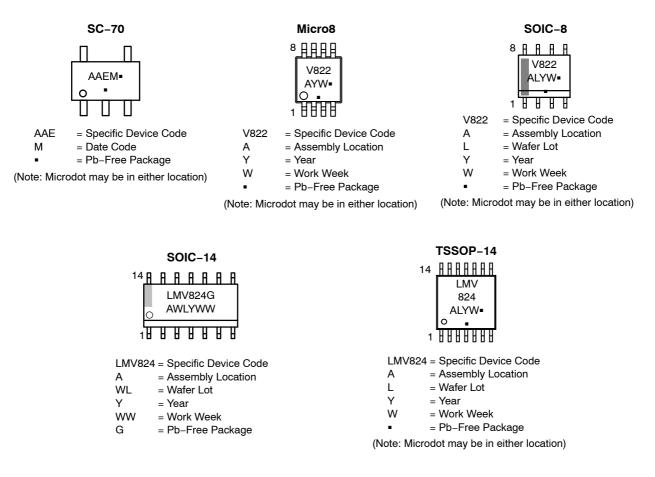


ORDERING AND MARKING INFORMATION

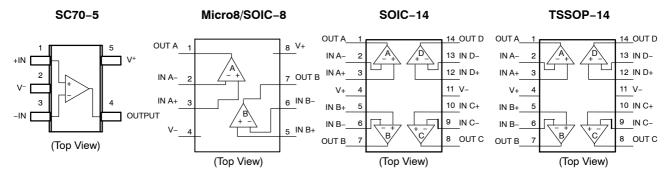
See detailed ordering and shipping information in the package dimensions section on page 11 of this data sheet.



MARKING DIAGRAMS



PIN CONNECTIONS



MAXIMUM RATINGS

Symbol	Rating	Value	Unit
VS	Supply Voltage (Operating Range V_S = 2.7 V to 5.5 V)	5.5	V
V _{IDR}	Input Differential Voltage	\pm Supply Voltage	V
V _{ICR}	Input Common Mode Voltage Range	–0.5 to (V+) +0.5	V
	Maximum Input Current	10	mA
t _{SO}	Output Short Circuit (Note 1)	Continuous	
TJ	Maximum Junction Temperature (Operating Range -40°C to 85°C)	150	°C
θ_{JA}	Thermal Resistance		°C/W
	SC-70	280	
	Micro8	238	
	SOIC-8	212	
	SOIC-14	156	
	TSSOP-14	190	
T _{STG}	Storage Temperature	-65 to 150	°C
Mounting Temperature (Infrared or Convection – 20 sec)		235	°C
V _{ESD}	ESD Tolerance Machine Model Human Body Model	200 2000	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

 Continuous short-circuit operation to ground at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Output currents in excess of 45 mA over long term may adversely affect reliability. Shorting output to either V+ or Vwill adversely affect reliability.

2.7V DC ELECTRICAL CHARACTERISTICS Unless otherwise noted, all min/max limits are guaranteed for $T_A = 25^{\circ}C$, V+ = 2.7 V, V- = 0 V, $V_{CM} = V+/2$, $V_O = V+/2$ and $R_L > 1 M\Omega$. Typical specifications represent the most likely parametric norm. Min/Max specifications are guaranteed by testing, characterization, or statistical analysis.

Parameter Symbol Conditions		Conditions	Min		Max	Unit
Input Offset Voltage	V _{IO}			1	3.5	mV
		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			4	
Input Offset Voltage Average Drift	TCV _{OS}			1		μV/°C
Input Bias Current	Ι _Β			105	210	nA
	[$T_A = -40^{\circ}C$ to $+85^{\circ}C$			315	
Input Offset Current	Ι _{ΙΟ}			0.5	30	nA
	[$T_A = -40^{\circ}C$ to $+85^{\circ}C$			50	
Common-Mode Rejection	CMRR	$0~V \leq V_{CM} \leq 1.7~V$	70	85		dB
Ratio	[$T_A = -40^{\circ}C$ to $+85^{\circ}C$	68			
Power Supply Rejection Ratio	PSRR	$1.5 \text{ V} \le \text{V}+ \le 4 \text{ V}, \text{V}-=-1 \text{ V}, \text{V}_{O}=0 \text{ V}, \\ \text{V}_{CM}=0.0 \text{ V}$	75	85		dB
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$	70			
Input Common–Mode Voltage Range	V _{CM}	For CMRR \ge 53 dB and T _A = -40°C to +85°C	-0.2	-0.3 to 2.0	1.9	V
Large Signal Voltage Gain	AV	R_L = 600 Ω,V_O = 0.5 V to 2.5 V	80	95		dB
		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	70			
		R_L = 2 kΩ, V_O = 0.5 V to 2.5 V	83	89		
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$	80			
Output Swing	V _{OH}	R_L = 600 Ω to 1.35 V	2.5	2.58		V
	[$T_A = -40^{\circ}C$ to $+85^{\circ}C$	2.4			
	V _{OL}	R_L = 600 Ω to 1.35 V		0.13	0.21	
	[$T_A = -40^{\circ}C$ to $+85^{\circ}C$			0.3	
	V _{OH}	$R_L = 2 k\Omega$ to 1.35 V	2.6	2.66		
	[$T_A = -40^{\circ}C$ to $+85^{\circ}C$	2.5			
	V _{OL}	$R_L = 2 k\Omega$ to 1.35 V		0.08	0.12	
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$			0.2	
Output Current	Ι _Ο	Sourcing, $V_0 = 0 V$	12			mA
		Sinking, $V_0 = 2.7 V$	12	26		
Supply Current	I _{CC}	LMV821 (Single)		0.242	0.3	mA
	[$T_A = -40^{\circ}C$ to $+85^{\circ}C$			0.5	
		LMV822 (Both Applications)		0.5	0.7]
	[$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			0.9]
		LMV824 (All Four Applications)		1	1.3]
	[$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			1.5]

2.5V DC ELECTRICAL CHARACTERISTICS Unless otherwise noted, all min/max limits are guaranteed for $T_A = 25^{\circ}C$, V+ = 2.5 V, $V_{-} = 0 V$, $V_{CM} = V_{+}/2$, $V_{O} = V_{+}/2$ and $R_{L} > 1 M\Omega$. Typical specifications represent the most likely parametric norm. Min/Max specifications are guaranteed by testing, characterization, or statistical analysis.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input Offset Voltage	V _{IO}	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		1	3.5	mV
					4	
Output Swing	V _{OH}	R_L = 600 Ω to 1.25 V	2.3	2.37		V
		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	2.2			
	V _{OL}	$\rm R_L$ = 600 Ω to 1.25 V		0.13	0.20	
		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			0.3	
	V _{OH}	$R_L = 2 \ k\Omega$ to 1.25 V	2.4	2.46		
		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	2.3			
	V _{OL}	R_L = 2 k Ω to 1.25 V		0.08	0.12	1
		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			0.20	1

2.7V AC ELECTRICAL CHARACTERISTICS Unless otherwise specified, all limits are guaranteed for $T_A = 25^{\circ}C$, V+ = 2.7 V, V- = 0 V, V_{CM} = 1.0 V, V_O = V+/2 and RL > 1 MΩ. Typical specifications represent the most likely parametric norm. Min/Max specifications are guaranteed by testing, characterization, or statistical analysis.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Slew Rate	SR	(Note 2)		1.5		V/uS
Gain Bandwidth Product	GBWP			5		MHz
Phase Margin	θ_{m}			55		0
Gain Margin	G _m			12.9		dB
Input-Referred Voltage Noise	e _n	f = 1 kHz, V _{CM} = 1 V		12		nV/√Hz
Input-Referred Current Noise	i _n	f = 1kHz		0.2		pA/√Hz
Total Harmonic Distortion	THD	f = 1 kHz, AV = –2, R_L = 10 $k\Omega$, V_O = 1.8 V_{PP}		0.023		%
Amplifier-to-Amplifier Isolation		(Note 3)		135		dB

2. Connected as voltage follower with input step from 0.5 V to 1.5 V. Number specified is the average of the positive and negative slew rates. 3. Input referred, $R_L = 100 \text{ k}\Omega$ connected to V+/2. Each amp excited in turn with 1kHz to produce V₀ = 3 V_{PP}. For Supply Voltages < 3 V, $V_0 = V+.$

5V DC ELECTRICAL CHARACTERISTICS Unless otherwise noted, all min/max limits are guaranteed for $T_A = 25^{\circ}C$, V+ = 5 V,V- = 0 V, VCM = V+/2, V_O = V+/2 and R_L > 1 M Ω . Typical specifications represent the most likely parametric norm. Min/Max specifications are guaranteed by testing, characterization, or statistical analysis.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input Offset Voltage	V _{IO}			1	3.5	mV
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$		1	4	
Input Offset Voltage Average Drift	TCV _{OS}			1		μV/°C
Input Bias Current	Ι _Β			119	245	nA
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$			380	
Input Offset Current	I _{IO}			0.5	30	nA
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$			50	
Common-Mode Rejection	CMRR	$0 \text{ V} \leq \text{V}_{\text{CM}} \leq 4.0 \text{ V}$	72	90		dB
Ratio		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	70	1		
Power Supply Rejection Ratio	PSRR	$\begin{array}{l} 1.7 \; V \leq V_{+} \leq 4 \; V, V_{-} = 1 \; V, V_{O} = 0 \; V, \\ V_{CM} = 0.0 \; V \end{array}$	75	85		dB
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$	70			
Input Common–Mode Voltage Range	V _{CM}	For CMRR \ge 58 dB and T _A = - 40°C to +85°C	-0.2	-0.2 to 4.3	4.2	V
Large Signal Voltage Gain	A _V	R_L = 600 Ω,V_O = 1.0 V to 4.0 V	87	100		dB
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$	73			
		R_L = 2 kΩ, V_O = 1.0 V to 4.0 V	84	99		
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$	82			
Output Swing	V _{OH}	R_L = 600 Ω to 2.5 V	4.75	4.84		V
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$	4.7			
	V _{OL}	R_L = 600 Ω to 2.5 V		0.17	0.33	
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$			0.4	
	V _{OH}	RL = 2 k Ω to 2.5 V	4.85	4.9		
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$	4.8			
	V _{OL}	$R_L = 2 \ k\Omega$ to 2.5 V		0.1	0.15	
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$			0.2	
Output Current	Ι _Ο	Sourcing, Vo = 0 V	20	45		mA
		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	10	1		
		Sinking, Vo = 5 V	20	40		1
		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	15	1		
Supply Current	Icc			0.3	0.4	mA
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$			0.6	1
		LMV822 (Both Applications)		0.5	0.7	1
		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			0.9	1
		LMV824 (All Four Applications)		1	1.3	1
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$			1.5	1

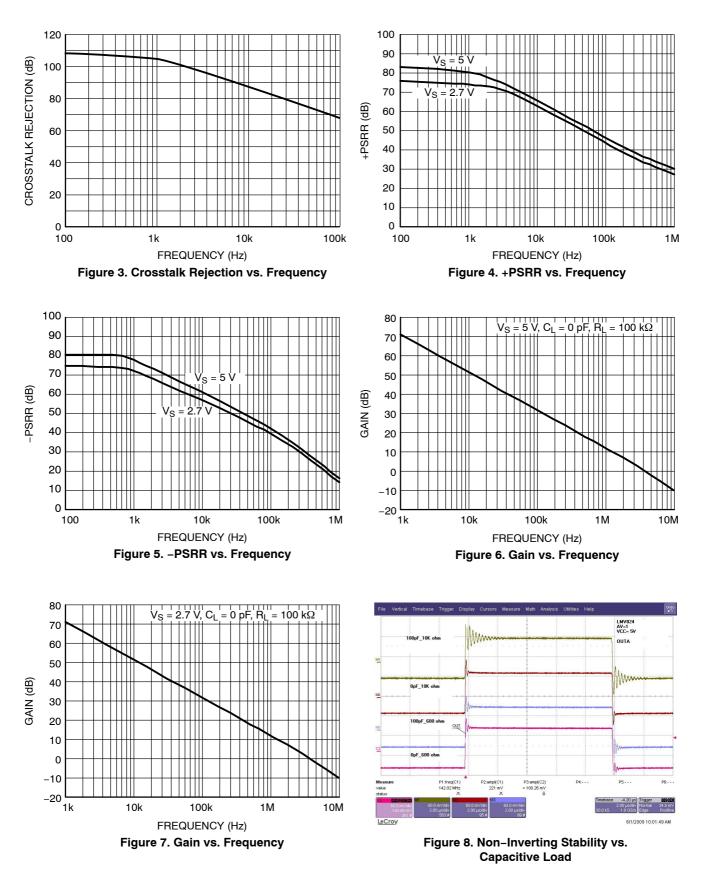
5V AC ELECTRICAL CHARACTERISTICS Unless otherwise specified, all limits are guaranteed for $T_A = 25^{\circ}C$, V+ = 5 V, V- = 0 V, V_{CM} = 2.0 V, V_O = V+/2 and R_L > 1 M Ω . Typical specifications represent the most likely parametric norm. Min/Max specifications are guaranteed by testing, characterization, or statistical analysis.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Slew Rate	SR	(Note 4)		2		V/µS
Gain Bandwidth Product	GBWP			5.6		MHz
Phase Margin	θ_{m}			63		0
Gain Margin	G _m			11.7		dB
Input-Referred Voltage Noise	e _n	f = 1 kHz, V _{CM} = 1 V		11		nV/√Hz
Input-Referred Current Noise	i _n	f = 1 kHz		0.21		pA/√ Hz
Total Harmonic Distortion	THD	f = 1 kHz, A_V = -2, R_L = 10 k\Omega , V_O = 4.11 VPP		0.012		%
Amplifier-to-Amplifier Isolation		(Note 5)		135		dB

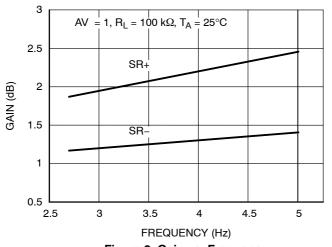
4. Connected as voltage follower with input step from 0.5 V to 3.5 V. Number specified is the average of the positive and negative slew rates.

5. Input referred, $R_L = 100 \text{ k}\Omega$ connected to V+/2. Each amp excited in turn with 1 kHz to produce $V_O = 3 \text{ V}_{PP}$. (For Supply Voltages < 3 V, $V_O = V_+$).

TYPICAL PERFORMANCE CHARACTERISTICS



TYPICAL PERFORMANCE CHARACTERISTICS



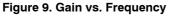




Figure 10. Non–Inverting Large Signal Step Response



Figure 11. Non–Inverting Small Signal Step Response

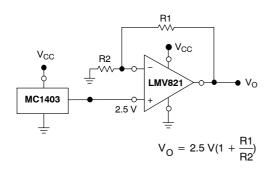


Figure 12. Inverting Large Signal Step Response

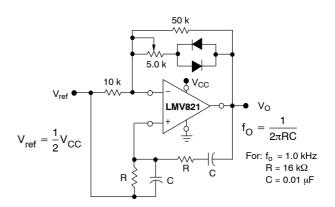




APPLICATIONS INFORMATION









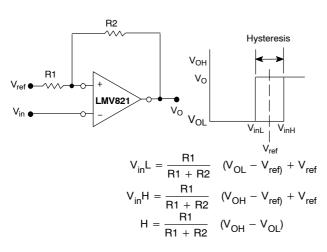
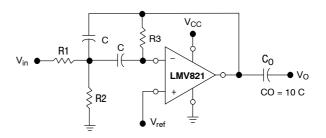
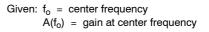


Figure 16. Comparator with Hysteresis





Choose value f_o, C
Then : R3 =
$$\frac{Q}{\pi f_0 C}$$

R1 = $\frac{R3}{2 A(f_0)}$
R2 = $\frac{R1 R3}{4Q^2 R1 - R3}$

For less than 10% error from operational amplifier, (($Q_O f_O$)/BW) < 0.1 where f_o and BW are expressed in Hz. If source impedance varies, filter may be preceded with voltage follower buffer to stabilize filter parameters.

Figure 17. Multiple Feedback Bandpass Filter

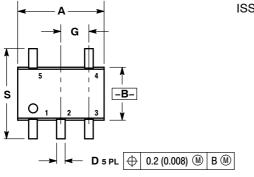
ORDERING INFORMATION

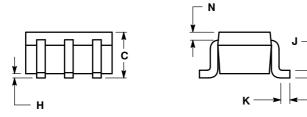
Order Number	Number of Channels	Specific Device Marking	Package Type	Shipping [†]
LMV821SQ3T2G*	Single	AAE	SC–70 (Pb–Free)	3000 / Tape & Reel
LMV822DMR2G*	Dual	V822	Micro8 (Pb–Free)	4000 / Tape & Reel
LMV822DR2G*	Dual	V822	SOIC-8 (Pb-Free)	2500 / Tape & Reel
LMV824DR2G	Quad	LMV824	SOIC-14 (Pb-Free)	2500 / Tape & Reel
LMV824DTBR2G	Quad	LMV 824	TSSOP-14 (Pb-Free)	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. *Contact factory.

SC-88A, SOT-353, SC-70

CASE 419A-02 ISSUE J

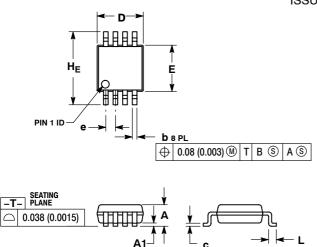




NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. 419A-01 OBSOLETE. NEW STANDARD 419A-02. 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INC	HES	MILLIN	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026	BSC	0.65	BSC
Н		0.004		0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20 REF	
S	0.079	0.087	2.00	2.20

Micro8TM CASE 846A-02 **ISSUE H**

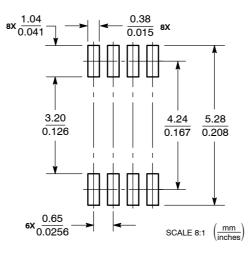


NOTES:

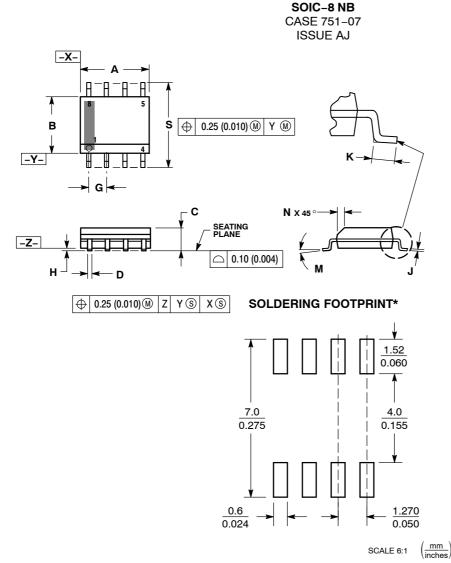
- I. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 JIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
 846A-01 OBSOLETE, NEW STANDARD 846A-02.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α			1.10			0.043
A1	0.05	0.08	0.15	0.002	0.003	0.006
b	0.25	0.33	0.40	0.010	0.013	0.016
c	0.13	0.18	0.23	0.005	0.007	0.009
D	2.90	3.00	3.10	0.114	0.118	0.122
E	2.90	3.00	3.10	0.114	0.118	0.122
е		0.65 BSC			0.026 BSC)
L	0.40	0.55	0.70	0.016	0.021	0.028
HE	4.75	4.90	5.05	0.187	0.193	0.199

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

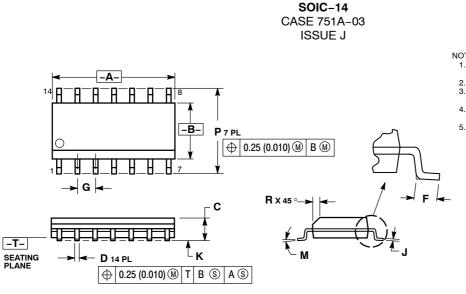


NOTES: 1. DIMENSIONING AND TOLERANCING PER

- ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION. З.
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) 4.
- MAXIMUM MOLD PROTRUSION 0.13 (0.005) PER SIDE.
 DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

31ANDARD 13731-07.							
	MILLIN	IETERS	INCHES				
DIM	MIN	MAX	MIN	MAX			
Α	4.80	5.00	0.189	0.197			
В	3.80	4.00	0.150	0.157			
С	1.35	1.75	0.053	0.069			
D	0.33	0.51	0.013	0.020			
G	1.27 BSC		0.05	0 BSC			
Н	0.10	0.25	0.004	0.010			
J	0.19	0.25	0.007	0.010			
κ	0.40	1.27	0.016	0.050			
М	0 °	8 °	0 °	8 °			
Ν	0.25	0.50	0.010	0.020			
S	5.80	6.20	0.228	0.244			

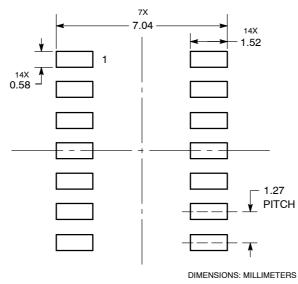
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



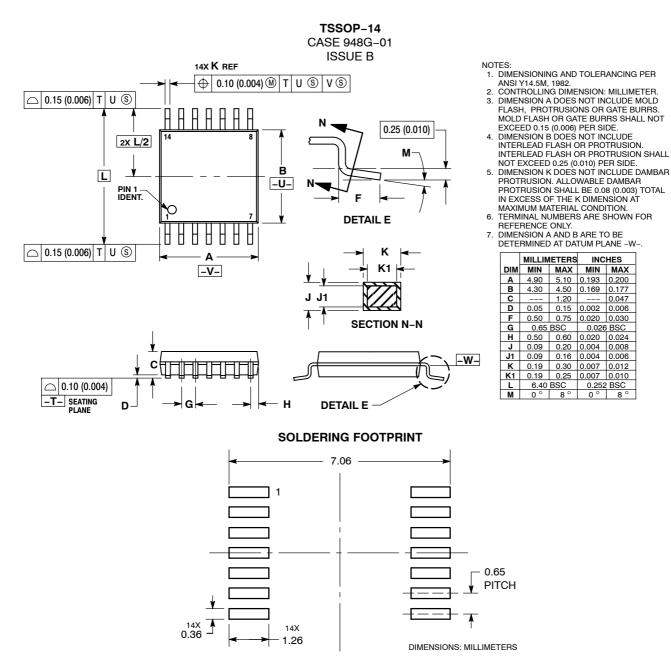
- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER. 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION. 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) DEED ELDE
- MAMMUM MOLE FITO INSIGN CLOCK OF PER SIDE.
 DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	8.55	8.75	0.337	0.344
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27	BSC	0.050 BSC	
J	0.19	0.25	0.008	0.009
κ	0.10	0.25	0.004	0.009
М	0 °	7 °	0 °	7 °
Ρ	5.80	6.20	0.228	0.244
R	0.25	0.50	0.010	0.019

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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6.40 BSC

0° 8

MIN MAX MIN MAX

4.90 5.10 0.193 0.200 4.30 4.50 0.169 0.177

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